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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/086,871	03/04/2002	Takumi Yamaguchi	60188-456	1896
7590	09/08/2006		EXAMINER	
McDermott Will & Emery 600 13th Street N W Washington, DC 20005-3096				NGUYEN, LUONG TRUNG
			ART UNIT	PAPER NUMBER
			2622	

DATE MAILED: 09/08/2006

Please find below and/or attached an Office communication concerning this application or proceeding.

Office Action Summary	Application No.	Applicant(s)
	10/086,871	YAMAGUCHI ET AL.
	Examiner	Art Unit
	LUONG T. NGUYEN	2622

-- The MAILING DATE of this communication appears on the cover sheet with the correspondence address --

Period for Reply

A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) OR THIRTY (30) DAYS, WHICHEVER IS LONGER, FROM THE MAILING DATE OF THIS COMMUNICATION.

- Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication.
- If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication.
- Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).

Status

- 1) Responsive to communication(s) filed on 13 June 2006.
- 2a) This action is FINAL. 2b) This action is non-final.
- 3) Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under *Ex parte Quayle*, 1935 C.D. 11, 453 O.G. 213.

Disposition of Claims

- 4) Claim(s) 1-20 is/are pending in the application.
- 4a) Of the above claim(s) _____ is/are withdrawn from consideration.
- 5) Claim(s) 1-12 is/are allowed.
- 6) Claim(s) 13-16 and 18-20 is/are rejected.
- 7) Claim(s) 17 is/are objected to.
- 8) Claim(s) _____ are subject to restriction and/or election requirement.

Application Papers

- 9) The specification is objected to by the Examiner.
- 10) The drawing(s) filed on _____ is/are: a) accepted or b) objected to by the Examiner.
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).
Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).
- 11) The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.

Priority under 35 U.S.C. § 119

- 12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).
- a) All b) Some * c) None of:
 1. Certified copies of the priority documents have been received.
 2. Certified copies of the priority documents have been received in Application No. _____.
 3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).

* See the attached detailed Office action for a list of the certified copies not received.

Attachment(s)

1) <input type="checkbox"/> Notice of References Cited (PTO-892)	4) <input type="checkbox"/> Interview Summary (PTO-413)
2) <input type="checkbox"/> Notice of Draftsperson's Patent Drawing Review (PTO-948)	Paper No(s)/Mail Date. _____ .
3) <input type="checkbox"/> Information Disclosure Statement(s) (PTO/SB/08)	5) <input type="checkbox"/> Notice of Informal Patent Application
Paper No(s)/Mail Date _____ .	6) <input type="checkbox"/> Other: _____ .

DETAILED ACTION

Response to Arguments

1. Applicant's arguments with respect to newly added claims 13-20, filed on 6/13/2006 have been fully considered but they are not persuasive. See discussion below.

Claim Objections

2. Claims 13-20 are objected to because of the following informalities:

Claim 13 (line 16), "a low level voltage" should be changed to --another low level voltage--.

Claims 14-20 are objected as being dependent on claim 13.

Appropriate correction is required.

Claim Rejections - 35 USC § 103

3. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negated by the manner in which the invention was made.

4. Claims 13-16, 18-20 are rejected under 35 U.S.C. 103(a) as being unpatentable over Ihara et al. (JP 10-093070) in view of Gowda (US 6,115,066).

Regarding claims 13, 18, Ihara discloses a solid state image sensor (solid state camera, see Abstract, figure 10, paragraph [0008]) comprising a plurality of amplifying unit pixels

arranged two-dimensionally on a semiconductor substrate, each of said plurality of amplifying unit pixels including a photoelectric conversion region (photodiode 115a, figure 10, paragraph [0008]) for subjecting incident light to photoelectric conversion; a read transistor (address transistor 117a, figure 10, paragraph [0008]) for reading signal charge obtained through the photoelectric conversion; a storage region (detecting element, which corresponds to floating diffusion FD, figure 10, paragraph [0008]) for storing said signal charge read by said read transistor; a detect transistor (magnification transistor 114a, figure 10, paragraph [0008]) for detecting said signal charge on the basis of application of potential of said storage region to a gate thereof; a reset transistor (reset transistor 116a, figure 10, paragraph [0008]) for resetting said signal charge stored in said storage region; and a drain region (drain line 112, figure 10, paragraph [0008]) for supplying a pulse voltage to said storage region through said reset transistor, a low level voltage applied to a gate of said read transistor of each pixel is set to voltage lower than a low level voltage to a gate of said reset transistor (since the claim does not define specific “a low level voltage,” the examiner reads limitation “a low level voltage” as broadest reasonable meaning “a voltage”. And noted that the voltage applied to the gate of address transistor 117a is set OFF when the voltage applied to the gate of reset transistor 116a is set ON in order to reset charge accumulated in the detecting element which connected to the gate of magnification transistor 114a. This indicates that the voltage applied to the gate of address transistor 117a is set lower than a voltage applied to the gate of reset transistor 116a, figure 10, paragraph [0008]).

Ihara et al. fails to specifically disclose wherein said drain regions of said plurality of amplifying unit pixels are connected to different drain lines row by row, and said drain line is

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pulse driven to be set to a HIGH level potential at least during a period when said signal charge stored in said storage region is reset and a period when said signal charge stored in said storage region is detected.

However, Gowda et al. teaches a CMOS image sensor, in which the drain regions VR of plurality pixels 30 are connected to different drain lines 34i row by row (figures 3, 4); and voltage level VR on bus line 34 (drain region) is set high during a period when charge in node 25 is transferred to column bus 15j (figures 4, 6, column 4, line 34 to column 5, line 8, column 6, lines 5-36). Therefore, it would have been obvious to one of ordinary skill in the art at the time the invention was made to modify the device in Ihara et al. by the teaching of Gowda et al. in order to reduce the size of a pixel of an image sensor. This reduces the size of the image sensor.

Regarding claim 14, Gowda et al. discloses wherein said drain line is set to a HIGH level potential during a period when said read transistor is in an ON state (VR is high when charge from node 25 read out to bus 15j, figures 4, 6).

Regarding claim 15, Gowda et al. discloses a vertical shift register for selecting one row of said plurality of amplifying unit pixels; and a circuit for supplying, to said drain line on a corresponding row, a power pulse generated by using an output from one stage of said vertical shift register (timing and control logic 14, figure 3, column 4, line 1 to column 5, line 8).

Regarding claim 16, Gowda et al. discloses a shift register for selecting one row or column of said plurality of amplifying wherein each of said unit pixels, plurality of amplifying

unit pixels is driven by a pulse used for driving said shift register (timing and control logic 14, figure 3, column 4, line 1 to column5, line 8).

Regarding claim 19, Gowda et al. discloses wherein said drain line is set to a HIGH level potential, for the purpose of removing unnecessary charge read from said photoelectric conversion region, during a period when said unnecessary charge is stored in said storage region and a period when said unnecessary charge stored in said storage region is reset (column 6, line 54 to column 5, line 20).

Regarding claim 20, Gowda et al. discloses wherein said drain line is set to a HIGH level potential, for the purpose of removing unnecessary charge read from said photoelectric conversion region to said storage region, during a period when both of said read transistor and said reset transistor are turned on (column 6, line 54 to column 5, line 20).

Allowable Subject Matter

5. Claims 1-12 are allowed.

The following is a statement of reasons for the indication of allowable subject matter:

Regarding claim 1, the prior art of the record fails to show or fairly suggest a solid state image sensor comprising wherein not less than two drain lines are set to a HIGH level potential during one blanking period for detecting signal charges of not less than two pixels adjacent to each other in a column direction out of said plurality of amplifying unit pixels.

Claims 2-12 are allowable for the reason given in claim 1.

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6. Claim 17 is objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.

Conclusion

7. **THIS ACTION IS MADE FINAL.** Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the mailing date of this final action.

8. Any inquiry concerning this communication or earlier communications from the examiner should be directed to LUONG T. NGUYEN whose telephone number is (571) 272-7315. The examiner can normally be reached on 7:30AM - 5:00PM.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, DAVID L. OMETZ can be reached on (571) 272-7593. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see <http://pair-direct.uspto.gov>. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

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09/04/06



DAVID OMETZ
SUPERVISORY PATENT EXAMINER